

L Number	Hits	Search Text	DB	Time stamp
1	2	capacitor\$2 and transistor\$2 and (planarization) and ((conformal or contour) adj (passivation or overcoat))and planarization and (gate adj line\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/05 12:21
-	2	6764900.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:46
-	2	6764900.pn. and (four or "4")	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:47
-	0	6764900.pn. and (four or "4" near5 transistor\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:48
-	0	6764900.pn. and (four or "4" near10 transistor\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:48
-	0	6764900.pn. and ((four) adj (transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:51
-	0	6764900.pn. and (four adj transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:53
-	2	6764900.pn. and ((6764900.pn. and (four or "4" near10 transistor\$3)) transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:56
-	0	6764900.pn. and ("4" adj transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:57
-	0	6764900.pn. and ("4" adj transistors)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:57
-	0	6764900.pn. and (four adj transistors)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 11:57
-	3	capacitor and transistor and (planarization adj layer) and ((conformal or conform\$3) adj (passivation adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 12:10
-	3	capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:18
-	4	capacitor and transistor and (planarization) and (conformal adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:34
-	0	438/155,200,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:35
-	1	438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and (conformal adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:36
-	1	438/155,200,239,241,256,279,393,399.ccls. and capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:43

-	0	250/59,214.1,370.09,580.ccls. and capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:44
-	0	257/295,312.ccls. and capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:45
-	4	capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:46
-	4	capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:47
-	2	capacitor and transistor and (planarization) and ((conformal or contour) adj passivation)and planarization and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:56
-	2	capacitor and transistor and (planarization) and ((conformal or contour) adj (passivation or overcoat))and planarization and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/05 12:20
-	2	capacitor and transistor and (planarization) and ((conformal or contour) adj (passivation or overcoat))and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 14:59
-	2	capacitor and transistor and (planarization) and ((conformal or contour) adj (passivation or overcoat))and (gate adj line) and (common adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 15:00
-	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 17:13
-	0	6060714.pn. and gray-photolithography	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 17:14
-	0	6060714.pn. and (gray-tone adj photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/08/04 17:15